

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP531, TLP532

PROGRAMMABLE CONTROLLERS

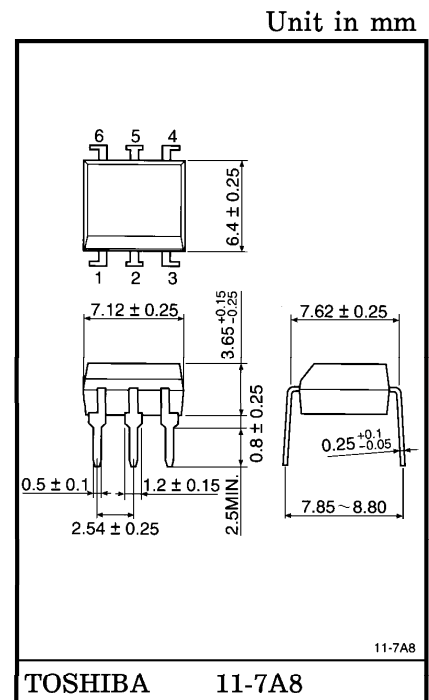
AC/DC-INPUT MODULE

SOLID STATE RELAY

The TOSHIBA TLP531 and TLP532 consist of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

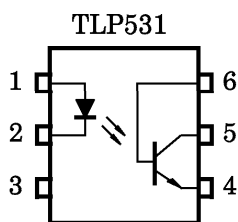
TLP532 is no-base internal connection for high-EMI environments.

- Collector-Emitter Voltage : 55V (Min.)
- Current Transfer Ratio : 50% (Min.)
Rank GB : 100% (Min.)
- Isolation Voltage : 2500V_{rms} (Min.)
- UL Recognized : UL1577, File No. E67349

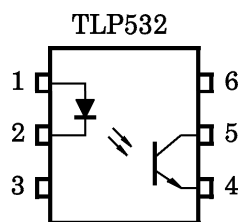


Weight : 0.4g

PIN CONFIGURATIONS (TOP VIEW)



1 : ANODE
2 : CATHODE
3 : N.C.
4 : EMITTER
5 : COLLECTOR
6 : BASE



1 : ANODE
2 : CATHODE
3 : N.C.
4 : EMITTER
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6 : N.C.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I _F	70	mA
	Forward Current Derating (Ta ≥ 50°C)	ΔI _F / °C	0.93	mA / °C
	Peak Forward Current (100μs pulse, 100pps)	I _{FP}	1	A
	Reverse Voltage	V _R	5	V
	Junction Temperature	T _j	125	°C
DETECTOR	Collector-Emitter Voltage	V _{CEO}	55	V
	Collector-Base Voltage (TLP531)	V _{CBO}	80	V
	Emitter-Collector Voltage	V _{ECO}	7	V
	Emitter-Base Voltage (TLP531)	V _{EBO}	7	V
	Collector Current	I _C	50	mA
	Power Dissipation	P _C	150	mW
	Power Dissipation Derating (Ta ≥ 25°C)	ΔP _C / °C	−1.5	mW / °C
	Junction Temperature	T _j	125	°C
Storage Temperature Range		T _{stg}	−55~125	°C
Operating Temperature Range		T _{opr}	−55~100	°C
Lead Soldering Temperature (10s)		T _{sol}	260	°C
Total Package Power Dissipation		P _T	250	mW
Total Package Power Dissipation Derating (Ta ≥ 25°C)		ΔP _T / °C	−2.5	mW / °C
Isolation Voltage (AC, 1min., R.H. ≤ 60%)		BV _S	2500	V _{rms}

RECOMMENDS OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{CC}	—	5	24	V
Forward Current	I _F	—	16	25	mA
Collector Current	I _C	—	1	10	mA
Operating Temperature	T _{opr}	−25	—	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 10\text{mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 5\text{V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
DETECTOR	Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.5\text{mA}$	55	—	—	V
	Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	$I_E = 0.1\text{mA}$	7	—	—	V
	Collector-Base Breakdown Voltage (TLP531)	$V_{(BR)CBO}$	$I_C = 0.1\text{mA}$	80	—	—	V
	Emitter-Base Breakdown Voltage (TLP531)	$V_{(BR)EBO}$	$I_E = 0.1\text{mA}$	7	—	—	V
	Collector Dark Current	I_{CEO}	$V_{CE} = 24\text{V}$	—	10	100	nA
			$V_{CE} = 24\text{V}, T_a = 85^\circ\text{C}$	—	2	50	μA
	Capacitance (Collector to Emitter)	C_{CE}	$V = 0, f = 1\text{MHz}$	—	10	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I_C / I_F	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$ Rank Y Rank YG Rank GR Rank GB Rank BL	50	200	600	%
			50	—	150	
			50	—	300	
			100	—	300	
			100	—	600	
			200	—	600	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 2.4\text{mA}, I_F = 8\text{mA}$	—	—	0.4	V

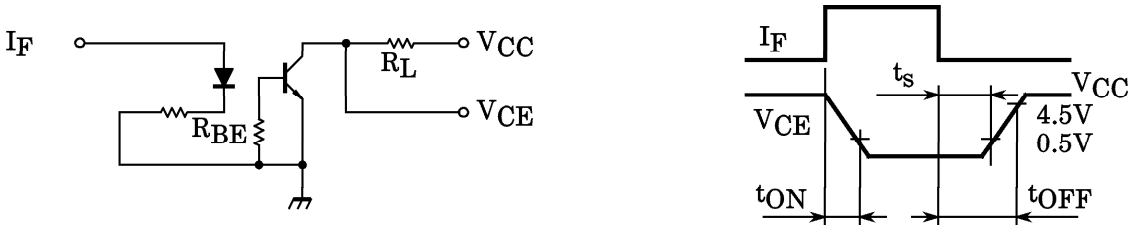
ISOLATION CHARACTERISTICS (Ta = 25°C)

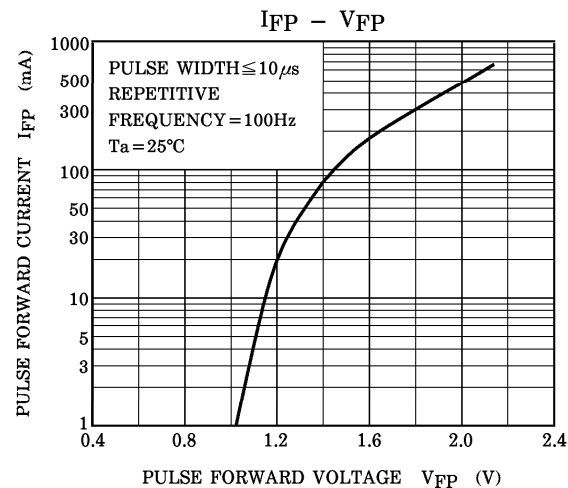
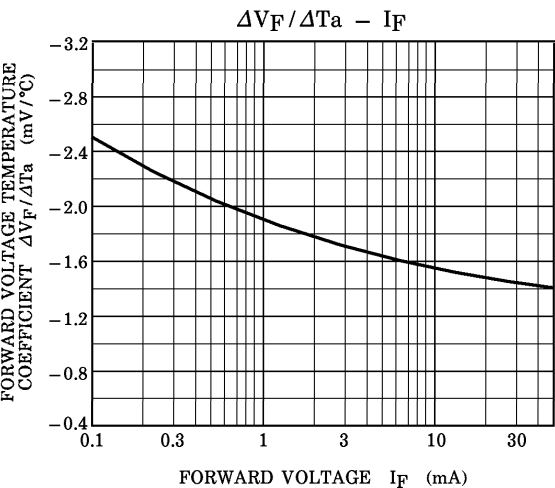
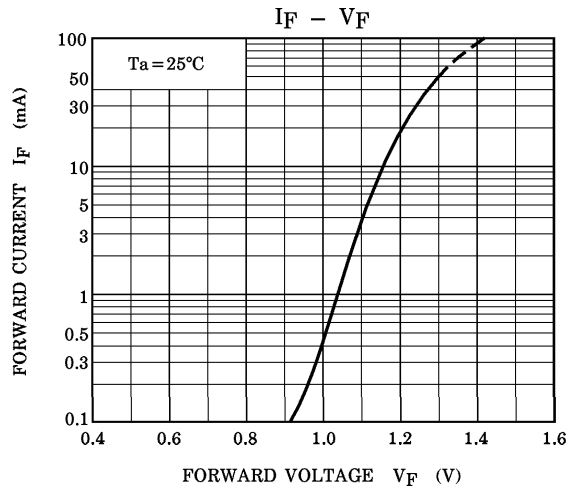
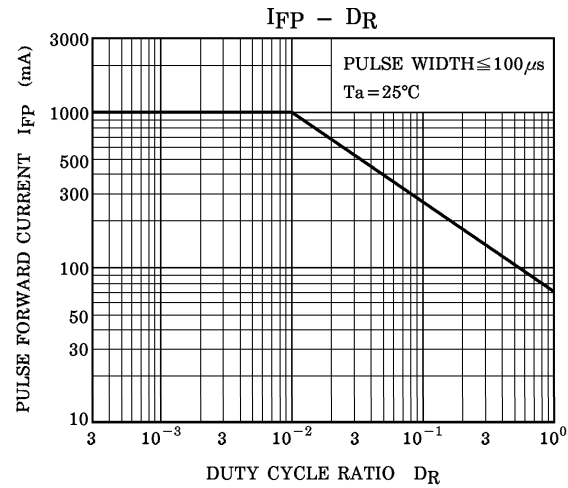
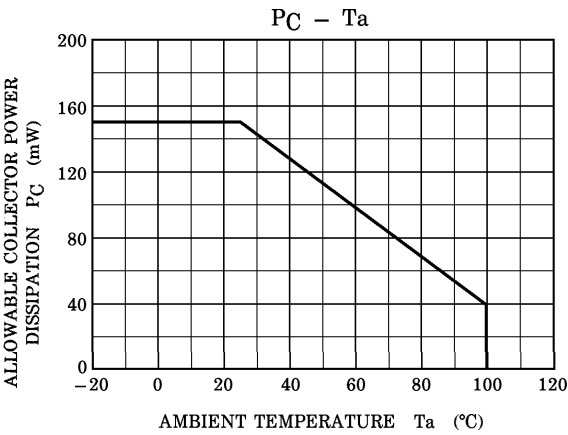
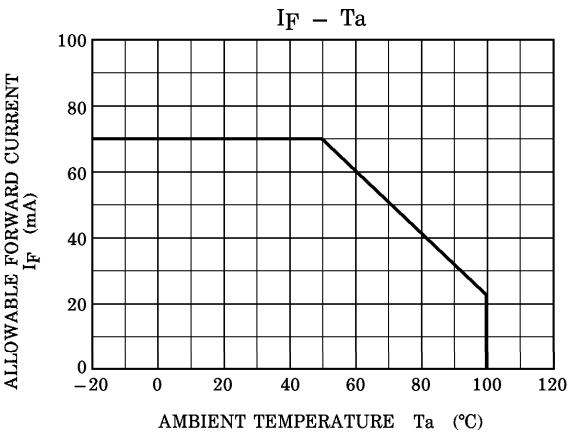
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	CS	VS=0, f=1MHz	—	0.8	—	pF
Isolation Resistance	RS	VS=500V, R.H.≤60%	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation Voltage	BVS	AC, 1 minute	2500	—	—	V _{rms}

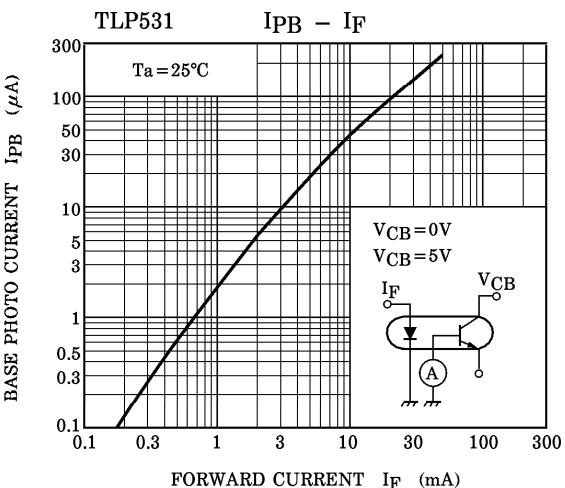
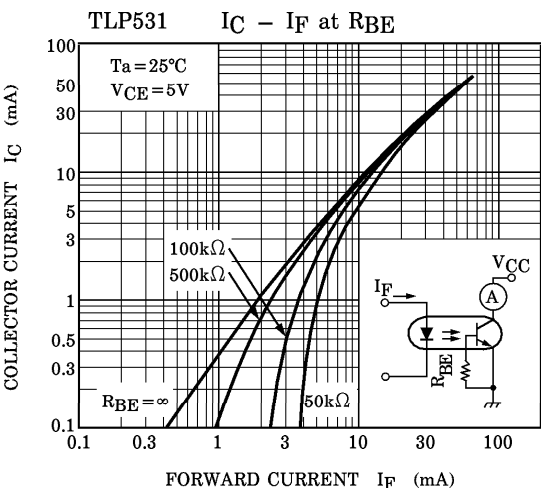
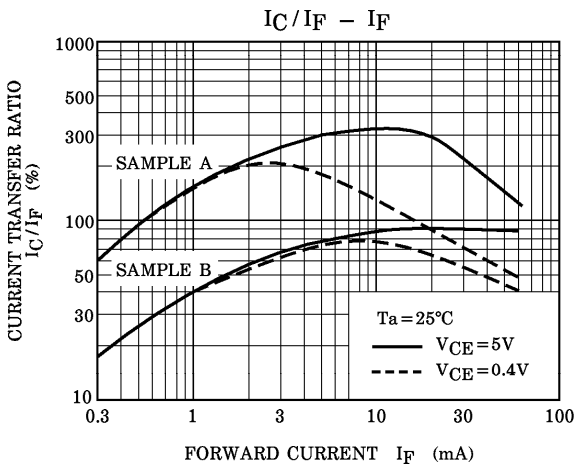
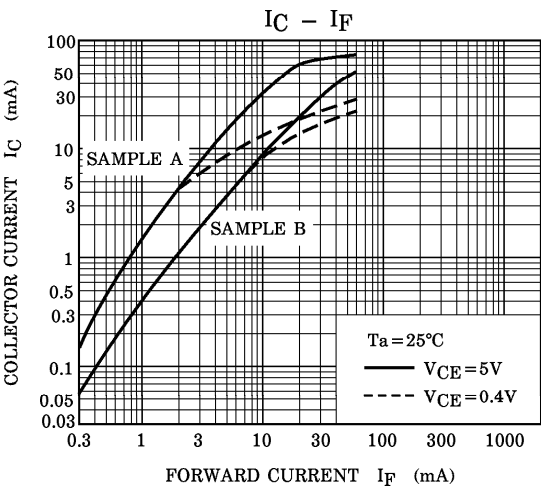
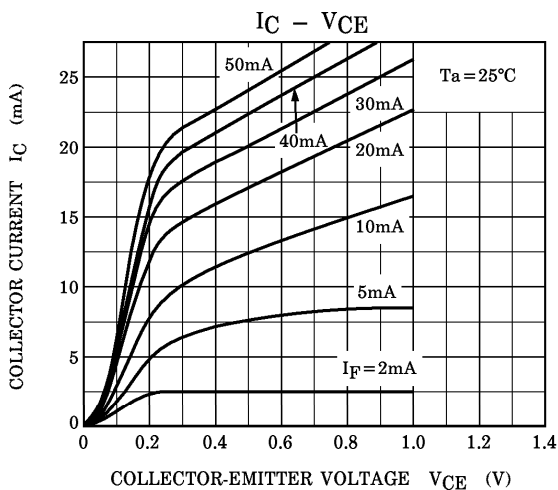
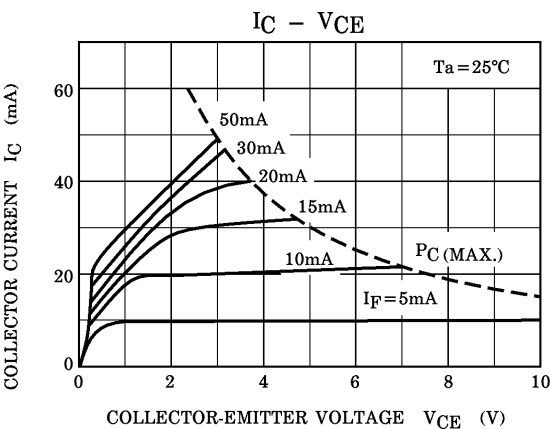
SWITCHING CHARACTERISTICS (Ta = 25°C)

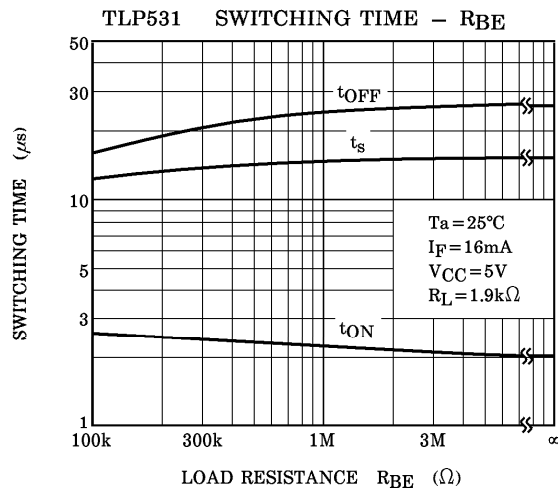
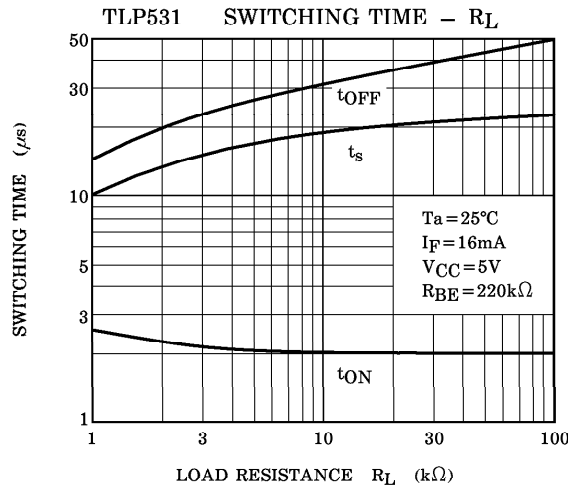
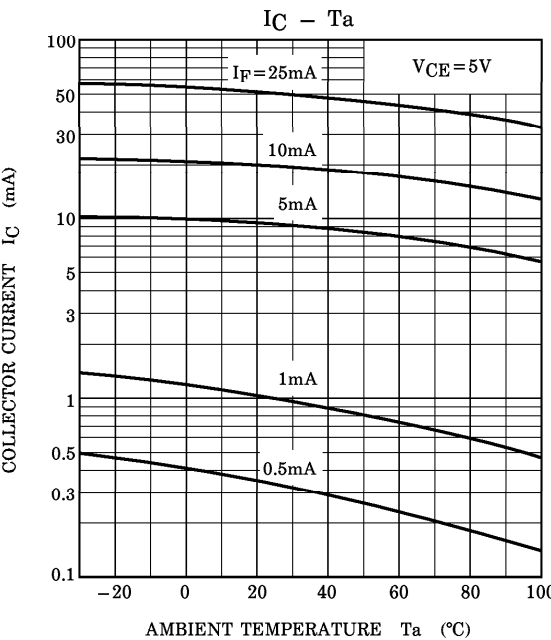
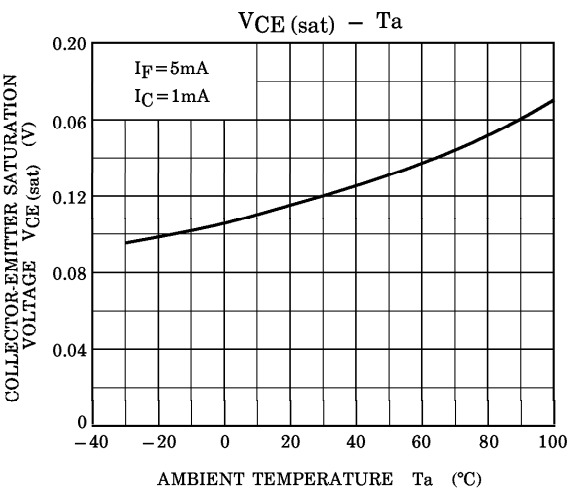
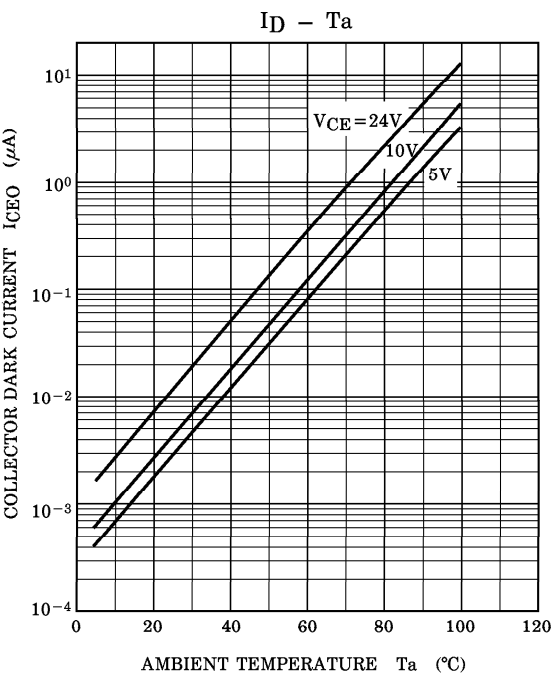
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Rise Time	t _r	VCC=10V IC=2mA RL=100Ω	—	2	—	μs
Fall Time	t _f		—	3	—	
Turn-on Time	t _{ON}		—	3	—	
Turn-off Time	t _{OFF}		—	3	—	
Turn-on Time	t _{ON}	RL=1.9kΩ (Fig.1) RBE=OPEN VCC=5V, IF=16mA	—	2	—	μs
Storage Time	t _s		—	15	—	
Turn-off Time	t _{OFF}		—	25	—	
Turn-on Time	t _{ON}	RL=1.9Ω (Fig.1) RBE=220kΩ (TLP531) VCC=5V, IF=16mA	—	2	—	μs
Storage Time	t _s		—	12	—	
Turn-off Time	t _{OFF}		—	20	—	

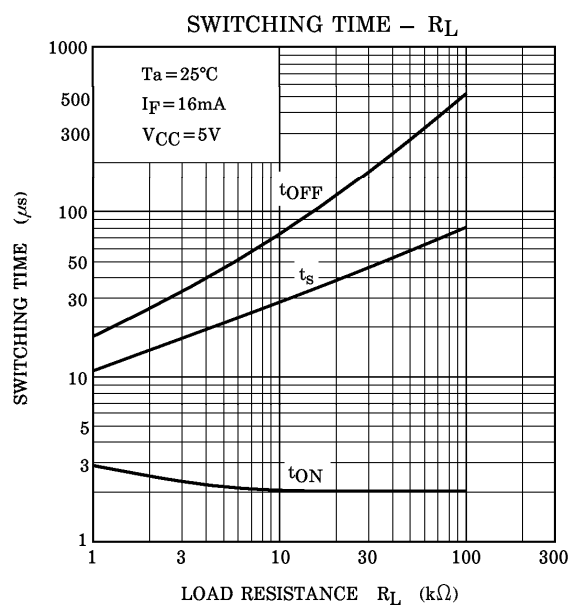
Fig.1 SWITCHING TIME TEST CIRCUIT











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